

TECHNICAL DATA DATA SHEET 4646, REV. -

# HERMETIC SCHOTTKY RECTIFIER Very Low Forward Voltage Drop

### Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

### **Maximum Ratings**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	45	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle, rectangular wave form (Single)	3.0	Α
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle, rectangular wave form (Common Cathode)	6	Α
Max. Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine wave (per leg)	55	Α
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C}, \ I_{AS} = 3.0  \text{A}, \ L = 4.4  \text{mH (per leg)}$	20	mJ
Repetitive Avalanche Current	I <sub>AR</sub>	$I_{AS}$ decay linearly to 0 in 1 $\mu$ s $f$ limited by $T_J$ max $V_A$ =1.5 $V_R$	3.0	А
Maximum Thermal Resistance	$R_{ heta JC}$	(Single) (Common Cathode)	2.97 5.95	°C/W
Max. Junction Temperature	$T_J$	-	-65 to +175	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-65 to +175	°C

### **Electrical Characteristics**

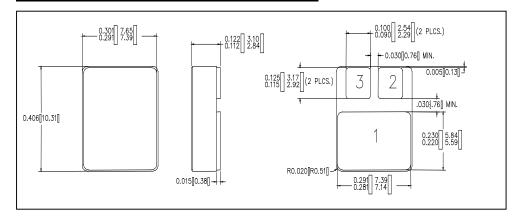
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 3.0A, Pulse, T <sub>J</sub> = 25 °C	0.69	V
(per leg)	$V_{F2}$	@ 3.0A, Pulse, T <sub>J</sub> = 125 °C	0.62	V
Max. Reverse Current	I <sub>R1</sub>	@V <sub>R</sub> = 45V, Pulse,	0.08	mA
		T <sub>J</sub> = 25 °C		
(per leg)	$I_{R2}$	$@V_R = 45V$ , Pulse,	3	mA
		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	C <sub>T</sub>	$@V_R = 5V, T_C = 25  ^{\circ}C$	160	pF
(per leg)		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		

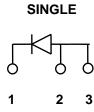


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# **Mechanical Dimensions: in Inches / mm**

### LCC-5





## **PINOUT TABLE**

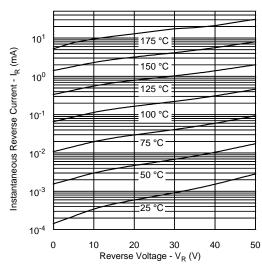
DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE

Note: The V<sub>f</sub> curves shown are for the SD60SB45 unpackaged die only.

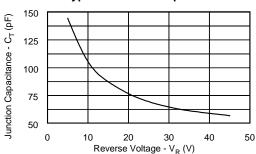
### **Typical Forward Characteristics**

# 10<sup>1</sup> - 175 °C - 125 °C - 125

### **Typical Reverse Characteristics**



### **Typical Junction Capacitance**





### **TECHNICAL DATA**

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